





20V PNP LOW SATURATION SWITCHING TRANSISTOR

Features and Benefits

- BV_{CEO} > -20V
- I_C = -3.5A Continuous Collector Current
- Low Saturation Voltage (-220mV max @ -1A)
- R_{SAT} = 64 mΩ for a low equivalent On-Resistance
- h_{FE} specified up to -6A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- R_θJA efficient, 60% lower than SOT23
- 4mm² footprint, 50% smaller than SOT23
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: DFN2020B-3
- Case Material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal Package Height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

Applications

- MOSFET Gate Driving
- DC-DC Converters
- Charging Circuits
- Power switches
- Motor control

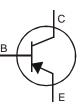




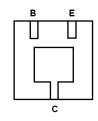




Bottom View



Device Symbol



Bottom View Pin-Out

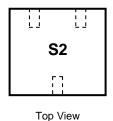
Ordering Information

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP718MATA	S2	7	8	3000
ZXTP718MATC	S2	13	8	10000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com

Marking Information



S2 = Product Type Marking code





Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit		
Collector-Base Voltage		V _{CBO}	-25			
Collector-Emitter Voltage		V _{CEO}	-20	V		
Emitter-Base Voltage		V _{EBO}	-7			
Peak Pulse Current		I _{CM}	-6			
Continuous Collector Current	(Note 3)	1-	-3.5			
Continuous Collector Current	(Note 4)	Ic	-4.0	_ ^		
Base Current		I _B	-1			

Thermal Characteristics @TA = 25°C unless otherwise specified

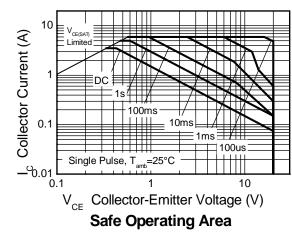
Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 3)	9	1.5 12	W	
Linear Derating Factor	(Note 4)	P _D	2.45 19.6	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 3)	D.	83		
Thermal Resistance, Junction to Ambient	(Note 4)	$R_{\theta JA}$	51	°C/W	
Thermal Resistance, Junction to Lead (Note 5)		$R_{ heta JL}$	16.8		
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

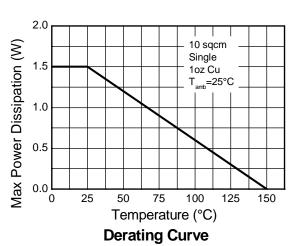
Notes:

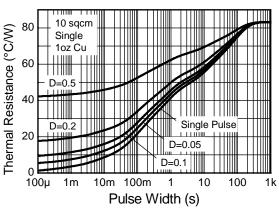
- 3. For a device surface mounted on 31mm x 31mm (10cm²) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
- 4. Same as note (3), except the device is measured at t ≤ 5 sec.
- 5. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).

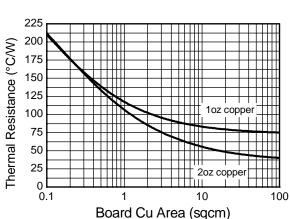


Thermal Characteristics



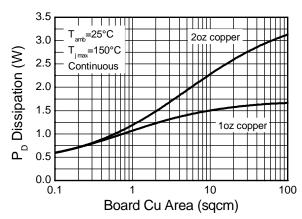






Transient Thermal Impedance

Thermal Resistance v Board Area



Power Dissipation v Board Area





Electrical Characteristics @T_A = 25°C unless otherwise specified

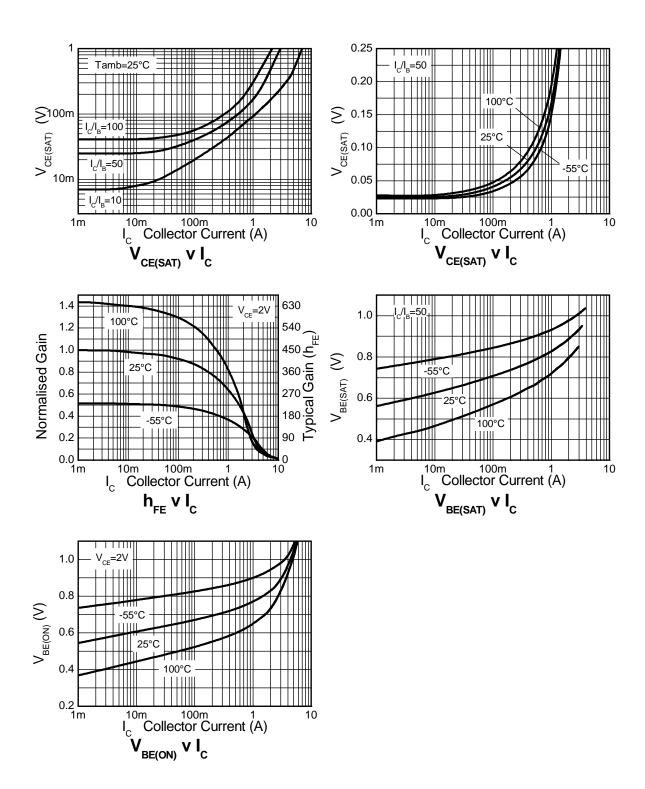
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-25	-35	-	V	I _C = -100 μA
Collector-Emitter Breakdown Voltage (Note 6)	BV_{CEO}	-20	-25	-	V	I _C = -10 mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.5	-	٧	I _E = -100 μA
Collector Cutoff Current	I_{CBO}	-	-	-100	nA	V _{CB} = -20V
Emitter Cutoff Current	I _{EBO}	-	-	-100	. nA	V _{EB} = -6V
Collector Emitter Cutoff Current	I _{CES}	-	-	-100	nA	V _{CES} = -16V
Static Forward Current Transfer Ratio (Note 6)	h _{FE}	300 300 150 15	475 450 230 30	- - -	-	$I_{C} = -10$ mA, $V_{CE} = -2$ V $I_{C} = -100$ mA, $V_{CE} = -2$ V $I_{C} = -2$ A, $V_{CE} = -2$ V $I_{C} = -6$ A, $V_{CE} = -2$ V
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}	- - - -	-19 -170 -190 -240 -225	-30 -220 -250 -350 -300	mV	I_C =- 0.1A, I_B = -10mA I_C = -1A, I_B = -20mA I_C = -1.5A, I_B = -50mA I_C = -2.5A, I_B = -150mA I_C = -3.5A, I_B = -350mA
Base-Emitter Turn-On Voltage (Note 6)	V _{BE(on)}	-	-0.87	-0.95	V	I _C = -3.5A, V _{CE} = -2V
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}	-	-1.01	-1.120	V	I _C = -3.5A, I _B = -350mA
Output Capacitance	C _{obo}	-	21	30	pF	V _{CB} =-10V. f = 1MHz
Transition Frequency	f _T	150	180	-	MHz	$V_{CE} = -10V, I_{C} = -50mA,$ f = 100MHz
Turn-On Time	t _{on}	-	40	-	ns	V _{CC} = -10V, I _C = -1A
Turn-Off Time	t _{off}	-	670	-	ns	$I_{B1} = I_{B2} = -10 \text{mA}$

Notes: 6. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



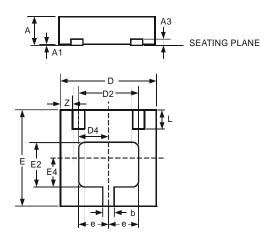


Typical Electrical Characteristics



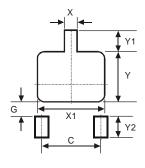


Package Outline Dimensions



DFN2020B-3					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0	0.05	0.02		
А3		_	0.152		
b	0.20	0.30	0.25		
D	1.95	2.075	2.00		
D2	1.22	1.42	1.32		
D4	0.56	0.76	0.66		
е		_	0.65		
Е	1.95	2.075	2.00		
E2	0.79	0.99	0.89		
E4	0.48	0.68	0.58		
L	0.25	0.35	0.30		
Z		_	0.225		
All D	All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)			
С	1.30			
G	0.24			
Х	0.35			
X1	1.52			
Υ	1.09			
Y1	0.47			
Y2	0.50			





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